**Monolithic Digital IC** 



## **Features and Functions**

- 3-channel magnet driver
- High current (2.0A max.) and low saturation voltage (1.5V)
- Parallel operation capability (channel 1 + 2)
- On-chip spark killer diodes

Absolute Maximum Ratings at T		unit		
Maximum Supply Voltage	V <sub>CC</sub> m	ax	8.0	v
Output Supply Voltage	V <sub>OUT</sub>		10.0	V
Input Supply Voltage	$V_{IN}$		12.0	V
Output Current	I <sub>OUT1</sub>	ton≦50ms,duty=20%, solenoid drive stage (ch1,2)	1.0	Α
	$I_{OUT2}$	ton≦50ms,duty=5%, motor drive stage (ch3)	2.5	Α
Spark Killer Diode Forward Current	I <sub>FSM1</sub>	t≦5ms,duty=5%, solenoid drive stage (ch1,2)	1.0	А
	I <sub>FSM2</sub>	$t \le 5$ ms, duty = 5%, motor drive stage (ch3)	2.5	А
V <sub>CC</sub> Instantaneous Flow-Out Current	I <sub>CCP</sub>	$t \leq 5 m s$ , $duty = 5\%$ ,	3.0	Α
GND Pin Flow-Out Current	I <sub>GND</sub>	$t \leq 5 m s, duty = 20\%$ ,	3.0	Α
Allowable Power Dissipation	Pd max		785	$\mathbf{mW}$
Operating Temperature	Topr		- 20 to + 75	°C
Storage Temperature	Tstg		-40 to +125	°C
Allowable Operating Range at 7		unit		
Supply Voltage	V <sub>CC</sub>		3.0 to 7.0	v
Input 'H'-Level Voltage	V <sub>IH</sub>	I <sub>OUT</sub> =300mA	3.0 to 11.0	v
Input 'L'-Level Voltage	V <sub>IL</sub>	I <sub>OUT</sub> ≦100μA	-0.3 to $+0.7$	v

## Package Dimensions 3001B-D8IC (unit : mm)



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Electrical Characteristics at Ta=25°C			min	typ	max	unit
Output Voltage	V <sub>OH1</sub>	$V_{IN} = 4.5 V, V_{CC} = 5.0 V,$			0.65	V
		$I_{OUT} = 500 \text{mA} (ch1,2)$				
	V <sub>OH2</sub>	$V_{IN} = 6.0V, V_{CC} = 7.0V,$			1.4	V
		I <sub>OUT</sub> =1000mA (ch1,2)				
	V <sub>OH3</sub>	$V_{IN} = 6.0V, V_{CC} = 7.0V,$			1.4	V
		I <sub>OUT</sub> =1600mA (ch1,2 parallel)				
	V <sub>OH4</sub>	$V_{IN} = 3.0 V, V_{CC} = 3.0 V,$			0.25	V
		$I_{OUT} = 300 \text{mA} \text{ (ch3)}$				
	V <sub>OH5</sub>	$V_{IN} = 4.5 V, V_{CC} = 5.0 V,$		0.5	0.7	V
		I <sub>OUT</sub> =1000mA (ch3)				
	V <sub>OH6</sub>	$V_{IN} = 6.0V, V_{CC} = 7.0V,$		. 1.0	1.5	V
		I <sub>OUT</sub> =2000mA (ch3)				
Input Current	I <sub>IN1</sub>	$V_{IN} = 6.0V (ch1, 2)$			1.0	mA
	$I_{IN2}$	$V_{IN} = 6.0V (ch3)$			2.0	mA
Power Source + Output	I <sub>OFF</sub>	$V_{IN} = 0.5 V, V_{OUT} = V_{CC} = 6.0 V$			30	μA
Leakage Current						
Spark Killer Diode	$V_{F1}$	$I_F = 1000 \text{ mA} \text{ (ch1,2)}$			3.0	V
Forward Voltage	V <sub>F2</sub>	$I_F = 2000 \mathrm{mA} \mathrm{(ch3)}$			3.0	V
Output Sustain Voltage	V <sub>O(sus)</sub>	I <sub>OUT</sub> =400mA	10			V

## Equivalent Circuit



Unit (resistance:  $\Omega$  )

≷ 900			P <sub>d</sub> max	- Т <sub>а</sub>		
2 200	785	_				
2 600				X		
Allowable Power Dissipation, Pd max - mw						
Ed 300						
5 300						
200						
Z ,	20	Ó Am	20 bient Tem	40 perature.'l	60 €a °C	75 80

## No.1281-2/3

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